

P-Channel MOSFET

Description

The PPMDP04R14L uses trench technology to provide excellent $R_{DS(ON)}$ low gate charge. This device is suitable for power management and high efficiency applications at high switching frequencies applications.

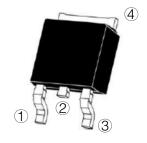
MOSFET Product Summary				
V _{DS} (V)	$R_{DS(on)}(m\Omega)(Typ)$	I _D (A)		
-40	14.5 @ V _{GS} = -10V	-50		
-40	17.5 @ V _{GS} = -4.5V	-50		

Feature

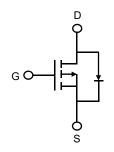
- > High Power and current handing capability
- > Lead free product is acquired
- > Surface Mount Package

Applications

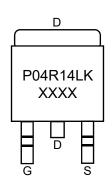
- > PWM applications
- Load Switch
- Power Management
- > DC-DC Converters
- Wireless Chargers



TO-252 (Top View)



Circuit Diagram



Marking (Top View)

Absolute maximum rating@25°C

Rating	Symbol	Value	Units	
Drain-Source Voltage		V _{DS}	-40	V
Gate-Source Voltage		V_{GS}	±20	V
Drain Current-Continuous ¹⁾	T _C =25°C	ı	-50	Α
Dialii Current-Continuous 7	T _C =100°C	I _D	-31.5	A
Pulsed Drain Current ²⁾	I _{DM}	-200	А	
Total Power Dissipation ³⁾		P_{D}	65.8	W
Avalanche Current ⁴⁾	I _{AS}	-28	Α	
Avalanche Energy ⁴⁾	iche Energy ⁴⁾		196	mJ
Thermal Resistance , Junction-to-Case ⁵⁾		$R_{ heta JC}$	1.9	°C/W
Thermal Resistance , Junction-to-Ambient ⁵⁾		$R_{\theta JA}$	38.4	°C/W
Junction and Storage Temperature Range	$T_{J,}T_{STG}$	-55~+150	°C	

Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units	
Off Characteristics							
Drain-Source Breakdown Voltage	BV _{DSS}	$V_{GS} = 0V, I_{D} = -250\mu A$	-40	-	-	V	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -40V, V_{GS} = 0V$	-	-	-1.0	μA	
Gate-Body Leakage Current	I _{GSS}	$V_{GS} = \pm 20 \text{V}, V_{DS} = 0 \text{V}$	-	-	±100	nA	
On Characteristics							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	-1.0	-1.5	-2.5	V	
Dunin Course On Chata Basistana	Б	V _{GS} = -10V,I _D = -20A	-	14.5	16.5		
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} = -4.5V,I _D = -15A - 17.5				- mΩ	
Dynamic Characteristics ⁶⁾							
Input Capacitance	C _{lss}		-	1980	-	pF	
Output Capacitance	C _{oss}	$V_{DS} = -20V, V_{GS} = 0V,$ f = 1.0MHz	-	167	-		
Reverse Transfer Capacitance	C _{rss}		-	123	-		
Switching Characteristics ⁶⁾							
Turn-on Delay Time	t _{d(on)}		-	8.3	-	ns	
Turn-on Rise Time	t _r	$V_{DS} = -20V, V_{GS} = -10V,$	-	51	-		
Turn-Off Delay Time	$t_{d(off)}$	$V_{DS} = -20V, V_{GS} = -10V,$ $R_{G} = 3\Omega, I_{D} = -15A$	-	80	-		
Turn-Off Fall Time	t _f		-	112	-		
Total Gate Charge	Q_g		-	30.2	-		
Gate-Source Charge	Q_{gs}	$V_{DS} = -20V, V_{GS} = -10V,$ $I_{D} = -15A$	-	5.8	-	nC	
Gate-Drain Charge	Q_{gd}		-	8.7	-		
Gate Resistance	R_g	f=1MHz, Open Drain	-	10.6	-	Ω	
Drain-Source Diode Characteristics							
Diode Forward Voltage	V _{SD}	$V_{GS} = 0V, I_{S} = -20A$	-	-0.8	-1.2	V	
Reverse Recovery Time	t _{rr}	1 = 200 d/d = 400 a/c	-	12.5	-	ns	
Reverse Recovery Charge	Q _{rr}	- I _F =-20A, d _i /d _t =100A/μs	-	3.9	-	nC	

Notes:

board design.

Repetitive Rating: Pulse width limited by maximum junction temperature(T_{J_Max}=150°C).

Pulse Test: Pulse Width ≤ 10μs, Duty Cycle ≤ 1%.

This single-pulse measurement was taken under the following condition [L=0.5mH,V_{GS}=-10V,V_{DS}=-20V]while it's value is limited by T_{J_Max}=150°C.

Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout.

Guaranteed by design, not subject to production.

Typical Characteristics

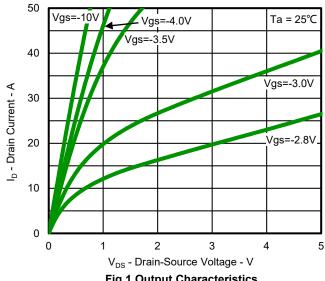


Fig.1 Output Characteristics

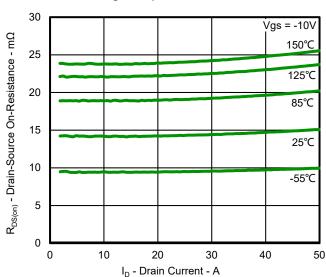


Fig.3 Typical On-Resistance vs Drain Current and Temperature

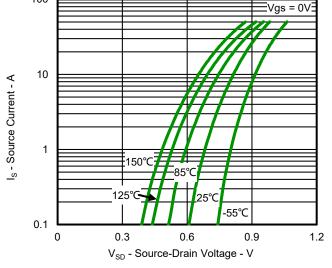


Fig.5 Diode Forward Voltage vs. Current

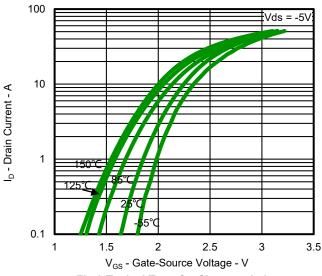


Fig.2 Typical Transfer Characteristic

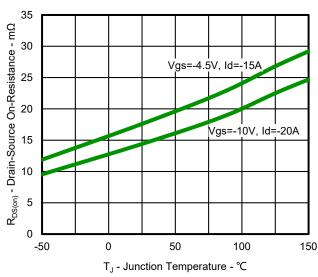


Fig.4 On-Resistance Variation with Temperature

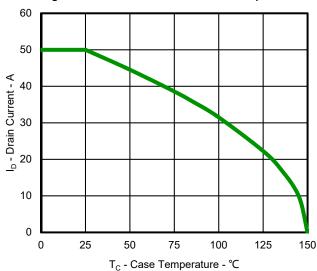
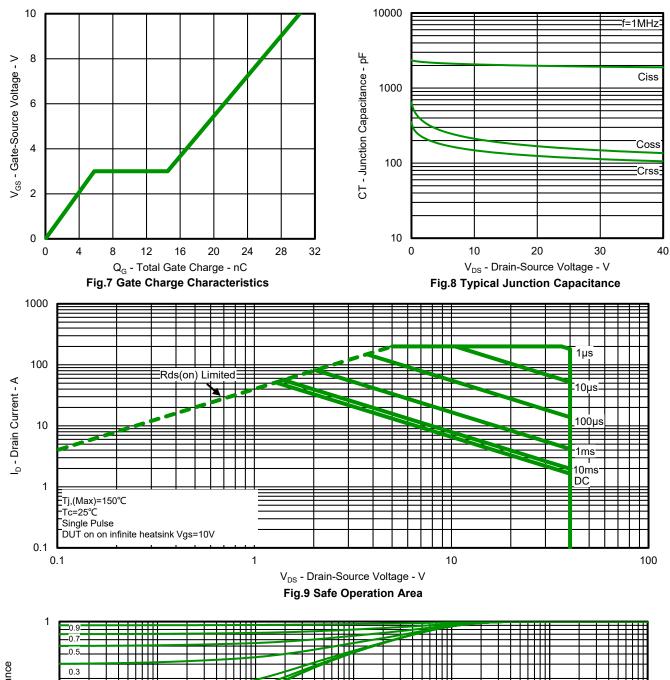


Fig.6 Maximum Drain Current vs. Case Temperature

P-Channel MOSFET

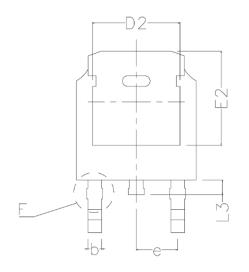
PPMDP04R14L

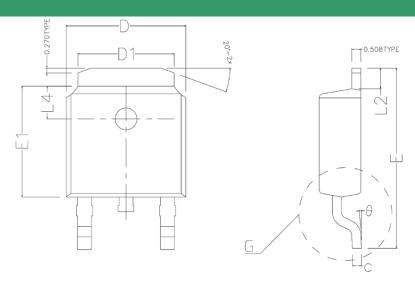


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Fig.10 Transient Thermal Resistance

Product Dimension (TO-252)



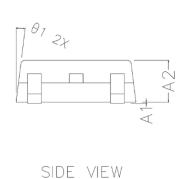


BOTTOM VIEW

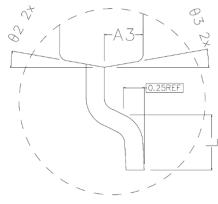


DETAIL F





SIDE VIEW



DETAIL G

Dim	Millimeters		Inches		Dim	Millim	neters	Inc	hes	
Dim	Min	Max	Min	Max	Dim	Min	Max	Min	Max	
A1	0.03	0.13	0.001	0.005	E2	5.14 Ref.		0.202 Ref.		
A2	2.20	2.40	0.087	0.094	е	2.286 Typ.		0.090 Typ.		
A3	0.96	1.06	0.038	0.042	L	1.40	1.60	0.055	0.063	
b	0.64	0.74	0.025	0.029	L2	1.00 Ref.		0.039 Ref.		
С	0.46	0.55	0.018	0.022	L3	0.80	Ref.	0.031	l Ref.	
D	6.50	6.70	0.256	0.264	L4	1.80 Ref.		0.071 Ref.		
D1	5.334	Ref.	0.210	Ref.	θ	0°	8°	0°	8°	
D2	4.83	Ref.	0.190	Ref.	θ1	7° Тур.		7° Typ.		
Е	9.77	10.17	0.385	0.400	θ2	7° Тур.		7° Typ.		
E1	6.00	6.20	0.236	0.244	θ3	7° Typ.		7° Typ. 7° Typ.		Гур.

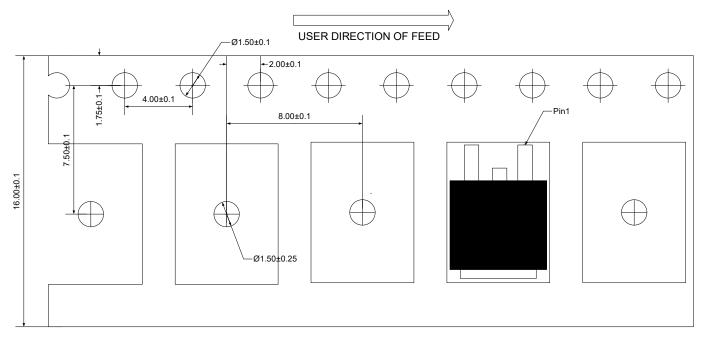
P-Channel MOSFET

PPMDP04R14L

Ordering Information

Package	Reel	Shipping
TO-252	13"	2500 / Tape & Reel

Load With Information



Unit:mm

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